

# MSA-0786

## Cascadable Silicon Bipolar MMIC Amplifier



### Data Sheet

#### Description

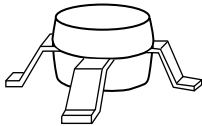
The MSA-0786 is a high performance silicon bipolar Monolithic Microwave Integrated Circuit (MMIC) housed in a low cost, surface mount plastic package. This MMIC is designed for use as a general purpose 50Ω gain block. Applications include narrow and broad band IF and RF amplifiers in commercial and industrial applications.

The MSA-series is fabricated using Avago's 10 GHz  $f_T$ , 25 GHz  $f_{MAX}$ , silicon bipolar MMIC process which uses nitride self-alignment, ion implantation, and gold metallization to achieve excellent performance, uniformity and reliability. The use of an external bias resistor for temperature and current stability also allows bias flexibility.

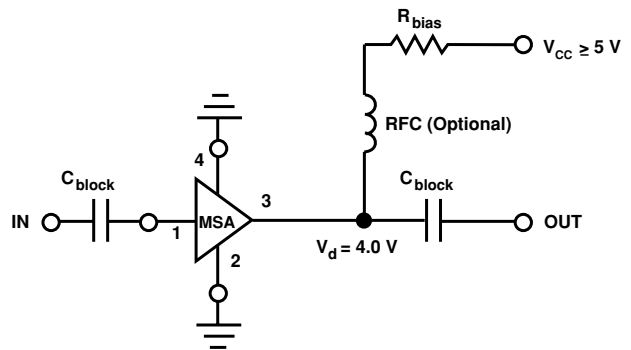
#### Features

- Cascadable 50Ω Gain Block
- Low Operating Voltage:  
4.0 V Typical  $V_d$
- 3 dB Bandwidth:  
DC to 2.0 GHz
- 12.5 dB Typical Gain at 1.0 GHz
- Unconditionally Stable ( $k > 1$ )
- Surface Mount Plastic Package
- Tape-and-Reel Packaging Option Available
- Lead-free Option Available

#### 86 Plastic Package



#### Typical Biasing Configuration



### MSA-0786 Absolute Maximum Ratings

Parameter	Absolute Maximum <sup>[1]</sup>
Device Current	60 mA
Power Dissipation <sup>[2,3]</sup>	275 mW
RF Input Power	+13 dBm
Junction Temperature	150°C
Storage Temperature	-65 to 150°C

#### Thermal Resistance<sup>[2]:</sup>

$$\theta_{jc} = 120^{\circ}\text{C}/\text{W}$$

#### Notes:

1. Permanent damage may occur if any of these limits are exceeded.
2.  $T_{\text{CASE}} = 25^{\circ}\text{C}$ .
3. Derate at  $8.3 \text{ mW}/^{\circ}\text{C}$  for  $T_{\text{C}} > 117^{\circ}\text{C}$ .

### Electrical Specifications<sup>[1]</sup>, $T_{\text{A}} = 25^{\circ}\text{C}$

Symbol	Parameters and Test Conditions: $I_{\text{d}} = 22 \text{ mA}$ , $Z_{\text{o}} = 50 \Omega$	Units	Min.	Typ.	Max.
$G_{\text{P}}$	Power Gain ( $ S_{21} ^2$ ) f = 0.1 GHz f = 1.0 GHz	dB	10.5	13.5 12.5	
$\Delta G_{\text{P}}$	Gain Flatness f = 0.1 to 1.3 GHz	dB		$\pm 0.7$	
$f_{3 \text{ dB}}$	3 dB Bandwidth	GHz		2.0	
VSWR	Input VSWR f = 0.1 to 2.5 GHz			1.7:1	
	Output VSWR f = 0.1 to 2.5 GHz			1.7:1	
NF	50 $\Omega$ Noise Figure f = 1.0 GHz	dB		5.0	
$P_{1 \text{ dB}}$	Output Power at 1 dB Gain Compression f = 1.0 GHz	dBm		5.5	
$\text{IP}_3$	Third Order Intercept Point f = 1.0 GHz	dBm		19.0	
$t_{\text{D}}$	Group Delay f = 1.0 GHz	psec		150	
$V_{\text{d}}$	Device Voltage	V	3.2	4.0	4.8
$dV/dT$	Device Voltage Temperature Coefficient	$\text{mV}/^{\circ}\text{C}$		-7.0	

#### Note:

1. The recommended operating current range for this device is 15 to 40 mA. Typical performance as a function of current is on the following page.

### Ordering Information

Part Numbers	No. of Devices	Comments
MSA-0786-BLK	100	Bulk
MSA-0786-BLKG	100	Bulk
MSA-0786-TR1	1000	7" Reel
MSA-0786-TR1G	1000	7" Reel

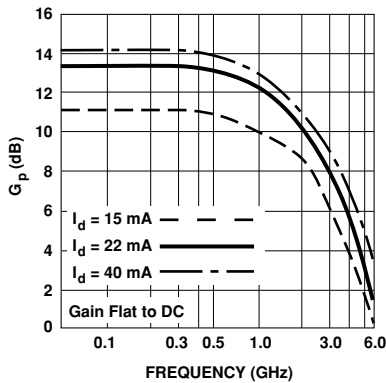
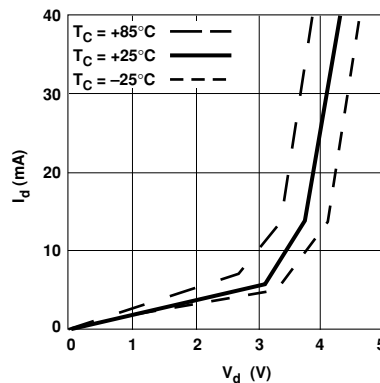
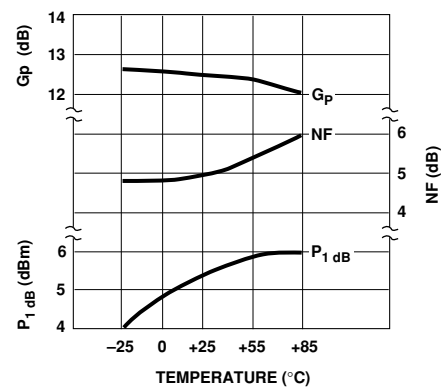
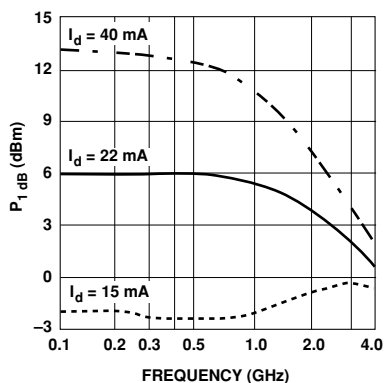
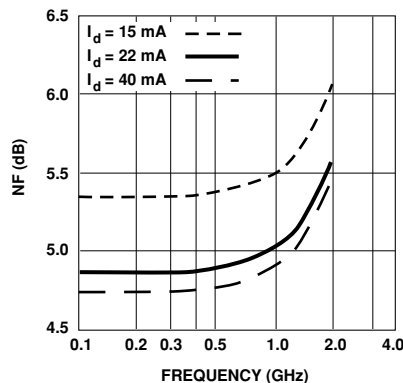
**Note:** Order part number with a "G" suffix if lead-free option is desired.

**MSA-0786 Typical Scattering Parameters ( $Z_0 = 50 \Omega$ ,  $T_A = 25^\circ\text{C}$ ,  $I_d = 22 \text{ mA}$ )**

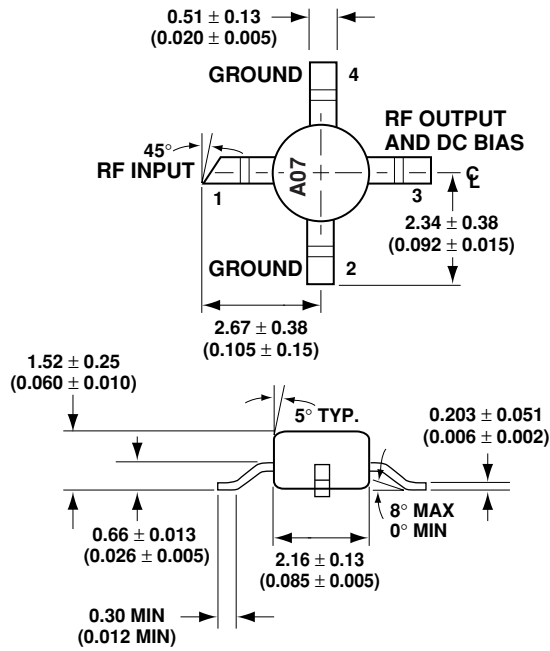
Freq. GHz	$S_{11}$		$S_{21}$			$S_{12}$			$S_{22}$	
	Mag	Ang	dB	Mag	Ang	dB	Mag	Ang	Mag	Ang
0.1	.05	175	13.5	4.74	174	-18.7	.116	1	.14	-12
0.2	.05	174	13.4	4.71	169	-18.7	.117	3	.14	-22
0.4	.04	167	13.3	4.64	158	-18.4	.120	4	.15	-44
0.6	.04	175	13.1	4.52	148	-18.3	.122	7	.16	-65
0.8	.05	-156	12.9	4.39	138	-18.0	.126	8	.17	-84
1.0	.06	-134	12.6	4.25	127	-17.5	.134	10	.18	-102
1.5	.08	-142	11.6	3.79	103	-16.6	.148	9	.21	-139
2.0	.15	-159	10.5	3.34	80	-15.7	.164	7	.23	-164
2.5	.25	-176	9.2	2.89	63	-15.1	.176	5	.24	174
3.0	.33	166	7.8	2.45	44	-14.7	.185	1	.24	159
3.5	.41	150	6.5	2.11	27	-14.9	.179	-5	.24	149
4.0	.49	137	5.2	1.82	12	-15.1	.177	-9	.23	145
5.0	.60	116	3.0	1.41	-14	-15.4	.169	-14	.26	145

**Typical Performance,  $T_A = 25^\circ\text{C}$** 

(unless otherwise noted)


**Figure 1. Typical Power Gain vs. Frequency.**

**Figure 2. Device Current vs. Voltage.**

**Figure 3. Output Power at 1 dB Gain Compression, NF and Power Gain vs. Case Temperature,  $f = 1.0 \text{ GHz}$ ,  $I_d = 22 \text{ mA}$ .**

**Figure 4. Output Power at 1 dB Gain Compression vs. Frequency.**

**Figure 5. Noise Figure vs. Frequency.**

## 86 Plastic Package Dimensions



DIMENSIONS ARE IN MILLIMETERS (INCHES)

For product information and a complete list of distributors, please go to our web site:  
[www.avagotech.com](http://www.avagotech.com)

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